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Optical and RIN Spectrum Improvements in Necked Waveguide High-Power DFB Laser Diode

Yihui Liu, Yongguang Huang, Ruikang Zhang, Lianping Hou, Senior Member, IEEE, Dan Lu, Lingjuan Zhao, Wei Wang, Member, IEEE

Abstract—A novel high power distributed feedback (DFB) laser is proposed which uses a partially narrow waveguide and corrugation pitch modulated (CPM) phase shift grating. Compared with conventional DFB lasers with constant waveguide width, these necked DFB lasers have greater improvements in terms of optical and relative intensity noise (RIN) spectrum. They are less sensitive to external optical feedback (EOF) and increase the range of the injection current for single longitudinal mode (SLM) operation. It can not only suppress the multimode lasing state under high injection current and EOF intensity, but also realize the SLM operation with RIN < -135 dB under a EOF intensity of less than -15 dB in the current range of 150 mA ~ 350 mA. Therefore, the range of injection current for SLM operation was increased for continuous wave (CW) light sources in silicon-based hybrid photonic integration applications.

Index Terms—coherent collapse, relative intensity noise (RIN), external optical feedback, high power DFB, continuous wave (CW), necked waveguide, corrugation pitch modulated (CPM).

I. INTRODUCTION

HIGH-power unilaterally-lasing continuous wave (CW) distributed feedback (DFB) lasers with external optical coupling have great application potential as light sources for silicon-based hybrid photonic integration. However, the external optical coupling will introduce unexpected reflections which can easily occur when there are refractive index discontinuities along the transmission direction [1]. In many circumstances, external optical feedback (EOF) from an external cavity may have a profound impact on the optical spectral linewidth and dynamic behavior of laser diodes (LDs) [2]. Several theoretical and experimental investigations on LD performances due to EOF have been performed before [3-6]. For stable single longitudinal mode (SLM) and superior low-noise laser operation, an expensive optical isolator is usually introduced and cascaded to the emitting face of the DFB laser to eliminate the EOF [7]. But this is not feasible in silicon-based hybrid photonic integration since most optical isolators cannot be monolithically fabricated. Therefore, one of the research topics is to design waveguide-based optical isolators capable of being integrated with LDs [8]. Another research direction is to develop DFB LDs which improve the resistance characteristics to EOF, expand the range of injection current for stable SLM of the isolator-free DFB LDs. Several methods have been reported, such as gain/complex-coupled DFB lasers [9], partially corrugated grating LDs (PC-LD) [10], quantum dot (QD) loss-coupled DFB laser with HR/HR coated facets [11], interband cascade lasers [12], and multi-period partially tilted grating FP lasers [13] etc. In this paper, we proposed a high-power DFB laser with high immunity to EOF. The proposed device is formed by inserting a section of narrow width waveguide in a conventional straight waveguide device, which is named as neck-ridged waveguide here. Within the narrow waveguide, there is a corrugation pitch modulated (CPM) phase-shift grating section. For comparison, we also proposed a straight waveguide CPM-DFB (S-CPM-DFB) laser with the same grating structure and cavity length fabricated on the same epitaxial layer. By comparing the performances in optical spectrum and relative intensity noise (RIN) of these two devices at the same EOF intensity, we found the necked waveguide with CPM grating DFB (N-CPM-DFB) laser had smaller sensitivity to EOF and the RIN resonance peaks are greatly reduced. The N-CPM-DFB LDs fabrication process is compatible with conventional DFB LDs, significantly reducing fabrication complexity and cost.

EOF is mainly considered as an external interference that affects the laser optical linewidth and noise level. LDs are intrinsically noisy devices because of the quantum nature of light. Even when biased at a constant current, the LD exhibits fluctuations in its phase and intensity due to temperature and aging. The effect of EOF is determined by many factors, such as feedback intensity, external reflected round-trip time, injection current and end facet reflectivity, etc. [1-3]. The EOF can lead to LD intensity and phase fluctuations, broaden or reduce the optical linewidth, and accordingly deteriorate or improve the signal-to-noise ratio (SNR) performance. These can be characterized by the optical and RIN spectrum [14]. When the EOF is less than -50 dB, the effect of the EOF phase on the spectral linewidth can be ignored [3]. Therefore, we mainly focus on the EOF intensity with a range of -10 dB ~ -50 dB.
II. DEVICE STRUCTURE AND MEASUREMENT SETUP

The waveguide and grating structure schematic diagrams of the S-CPM-DFB and N-CPM-DFB lasers are shown in Fig. 1. They both have the same cavity length of 1000 μm with anti-reflective (AR) coating (0.12%) and high-reflective (HR) (98.74%) coated on the facets of the devices. The active region is composed of AlGaInAs strained multiple quantum wells (MQWs) with a center wavelength of around 1310 nm. The uniform gating period was 203.5 nm and the CPM grating period was 203.6 nm which was used to produce effective 1/4 phase shift (λ denotes the Bragg wavelength), both of which are defined by electron beam lithography (EBL) and reactive ion etching (RIE) process. For the N-CPM-DFB laser, the necked waveguide is 100 μm long and overlaps with CPM grating segment with 5 μm long tapered section at both sides of the necked section. The narrowed ridge segment is 2.1 μm wide with a grating coupling coefficient κ around 14.6/cm, and the other sections are 2.5 μm wide with a κ value around 17/cm. The S-CPM- DFB laser has the same grating layout but with a constant waveguide width of 2.5 μm with a κ value around 17/cm.

![Fig. 1. Schematical diagram of S-CPM-DFB LD (left) and N-CPM-DFB LD (right) waveguide and grating structures.](image)

![Fig. 2. Schematic diagram of tunable feedback optical circuit testing setup.](image)

Fig. 2 shows the setup to tune the intensity of the EOF and measure the optical spectrum and RIN of the devices with EOF. The test LDs was stuck onto the chip carrier with a temperature control (TEC) stage underneath (25°C). The output light of the LD was coupled to a tapered optical fiber and then entered to Splitter 1 which has 1% light entering the power meter and 99% entering the circulator. The optical power-meter was used for real-time measurement of the total optical power coupled into the optical fiber. The light from port 3 of the circulator then entered Splitter 2 which evenly divided the input light into two parts, one for optical feedback loop, and another one for multiparameter measurements, such as optical spectrum and RIN. Since the system was dynamically balanced, the light output from the circulator is under a EOF modulated state. The feedback ratio was controlled by using a variable optical attenuator (VOA). A polarization controller (PC) was used to adjust the polarization of the feedback light to obtain the maximum feedback effect under a given feedback level to reach the worst situation for the laser. The lowest RIN floor of the measurement machine is around -150 dB, and the RIN detector maximum input power should not exceed 3 dBm, therefore an adjustable attenuator was placed in front of RIN detector. Eq. (1) was used to calculate EOF intensity of the system:

\[ A_{\text{system}} = A_{\text{coupling}} \times 2 + A_{\text{splitter1}} + A_{\text{splitter2}} + A_{\text{VOA}} \]  

(1)

\( A_{\text{system}} \) is the total intensity of the system return optical feedback; \( A_{\text{splitter1}} \) and \( A_{\text{splitter2}} \) are the losses of the beam Splitter 1 and Splitter 2, which were fixed values. \( A_{\text{VOA}} \) is the tunable loss introduced by the VOA; \( A_{\text{coupling}} \) is the coupling loss between the LDs and the tapered fiber which make sure it a constant value of -3.5 dB. The whole EOF round-trip loop length is 130 cm with a fixed delay time of 6.4 ns.

III. EXPERIMENTAL RESULTS AND ANALYSIS

At 25°C, the threshold currents of S-CPM-DFB and N-CPM-DFB are 29.5 mA and 26.9 mA respectively. Under 400 mA, their output powers are 97.2 mW and 97.4 mW, respectively. For comparison, the optical and RIN spectra were measured for the 1mm long DFB LD with a uniform grating and an abrupt 1/4 phase shift at 330 μm from the HR coated facet, which was fabricated using the same wafer and same facets’ reflectivity.

![Fig. 3. Measured optical spectrum and RIN.](image)
coherent collapse region, the LD tended to be unstable, behaving as a wide emission spectrum and having a considerable frequency fluctuation and increasing the overall noise intensity which was confirmed by increasing 20 dB in the RIN level of the relaxation oscillation peak (much pronounced in Fig.4(a) at 300 mA). The RIN curve contains multiple oscillation peaks, and their frequencies correspond to resonance frequency 6.18 GHz and its multiple value [15]. When decreasing the EOF intensity, the DFB laser can maintain a stable SLM operation. At -20 dB EOF intensity, the LD did not transit to the coherent collapsed state until an injection current of 400 mA, where the resonant peak of the RIN appears around the double resonance frequency, i.e., 12.34 GHz. As the EOF intensity was further reduced, such as below -25 dB, the LD was able to keep the SLM operation stable in the injection current range of 150 mA ~ 400 mA, with RIN < -140 dB. The effect of the EOF to the S-CPM-DFB was much more pronounced under a larger bias current. It even entered the multi-mode lasing state under high injection current range, which severely limited the effective operating current range in practical application.

In comparison, even under a strong EOF of -10 dB, N-CPM-DFB laser will not be deteriorated to a multi-mode lasing state (see Fig.3(b) and Fig.4(b)). Even under high injection current, its critical current value for coherent collapse has also improved significantly. Within the current range of 150 mA ~ 350 mA, the optical spectrum keeps a SLM with side mode suppression ratio (SMSR) > 45 dB. As the laser power increases, the feedback intensity range corresponding to the coherent collapse region became smaller. This can be qualitatively understood since the instability is driven by spontaneous emission and the effects of EOF noise are reduced when laser power increases, due to improved photon statistics. In addition, the photon distribution along the cavity has been improved due to the introduction of the necked waveguide, the effect of EOF noise is reduced when the laser power is increased. Apart from this, N-CPM-DFB laser can quickly move to a stable SLM state as the EOF intensity decreases. When EOF is below -15 dB, the N-CPM-DFB laser has a SLM operation with SMSR > 40 dB in the current range of 150 mA ~ 400 mA, and the RIN is less than -142 dB.

From Fig.3 (a) and Fig.4 (a), S-CPM-DFB LD can only achieve stable SLM from 150 mA to 300 mA under less than -25 dB EOF intensity. When strong feedback (-10 dB) was applied to the S-CPM-DFB LD, it transited a stable single-mode and then transited to a coherent collapse mode [5] when the injection current was increased which initiated multi-mode lasing at a current of more than 350 mA. The noise and linewidth of the device was further deteriorated [16]. In the
III is a SLM area, and IV represents the coherent collapse area. It is obvious that the N-CPM-DFB laser has a wider range of SLM area than that of the S-CPM-DFB LD and did not show the multimode lasing state even under 400 mA and -10 dB EOF.

Fig. 6. RIN of S-CPM-DFB, N-CPM-DFB, and ¼ phase shift DFB LDs at a current of 200 mA, 300 mA, 400 mA when the EOF intensity was changed from -10 dB to -50 dB in steps of -5 dB.

The primary source of the intensity noise in the LD is the spontaneous emission that is usually amplified due to the external feedback effect. The joint effect of the internal and external cavity is based on optimizing the resonance between photons and carriers to suppress RIN [15]. For N-CPM-DFB lasers, the introduction of a necked waveguide in the CPM section leads to less sensitivity to the effect of the CPM phase mismatching and didn’t reduce the effective grating coupling coefficient. Therefore, the intensity distribution along the cavity is flatter and the spatial hole burning effect is alleviated, reducing the strong effect of the EOF in the entire cavity.

Many studies have shown that the feedback sensitivity of the lasers was evaluated from the stability of the longitudinal mode shape, the optical field depends only on the phase of the HR facet [9]. Therefore, the necked waveguide is designed near the HR facet, which more efficiently suppresses the uneven distribution of photons and carriers. The N-CPM-DFB LD can be further optimized, such as the waveguide width of the necked section, the length of the necked section, the distance between the necked section and the HR surface, the grating duty ratio of the CPM section, etc. A more robust N-CPM-DFB LD could be achieved even under larger EOF intensity.

IV. CONCLUSION

A robust N-CPM-DFB LD was proposed and characterized in terms of the optical and RIN spectrum by a tunable feedback optical circuit test system. Compared with the S-CPM-DFB LDs, the necked waveguide combined with the CPM phase shift grating increased resistance to EOF. It can not only suppress the multimode lasing state under high injection current and strong EOF, but also realize the SLM operation with RIN < -135 dB under the EOF intensity of less than -15 dB in the current range of 150 mA ~ 350 mA. Therefore, it will increase the range of the injection current for SLM operation as CW light sources for silicon-based hybrid photonic integration application.

REFERENCES